

tive object. Further, the sensor provides reliable touch sensing through moisture, dirt or other contaminants on the touch screen surface.

[0033] The touch sensor of the present invention is particularly useful when combined with various types of data processing systems. The data processing systems incorporating the touch sensor of the present invention may include a display device enhanced by a transparent touch screen, for example. Such systems may be used in kiosks, ATMs, and a variety of point of sale devices. Further, desktop, handheld or laptop computer systems may incorporate a touch sensor of the present invention. The touch sensor may also be implemented in a personal data assistant (PDA) or a cell phone. Although the touch sensing device is described in combination with a microprocessor-based system, the touch sensing device may be combined with any logic-based system, if desired. The systems and methods of the present invention may be implemented with controller circuitry that uses a capacitively coupled connection to earth ground, or with a simplified controller that uses an internal low impedance reference.

[0034] In one embodiment, the touch sensor of the present invention includes two conductive layers disposed in a touch area and defining a gap between the two layers. A location of the touch input is determined by a change in capacitance between the two layers. The touch sensing method of the present invention includes deflecting a first conductive layer in the direction of a second conductive layer and detecting the location of the deflection. The basic operation of a touch sensor of the present invention is illustrated in FIGS. 1A and 1B. The touch sensor includes, at least, a top conductive layer 110 and a bottom conductive layer 120 separated by a gap 115. The top and bottom conductive layers 110, 120 form the capacitor plates of the capacitive touch sensor 100. Prior to a touch, the top and bottom conductive layers 110, 120 are typically positioned so that they are sufficiently separated, as shown in FIG. 1A. When touched with sufficient force, one conductive layer is locally deflected towards the other conductive layer, but is not brought into physical contact with the other layer. In the example shown in FIG. 1B, the top conductive layer 110 is deflected in the direction of the bottom conductive layer 120. The deflection of the top conductive layer causes the distance between the conductive layers 110, 120 to decrease at the location of the touch, thereby changing the capacitance between the top and bottom conductive layers 110, 120 in a local area around the point of deflection. The change in capacitance is detectable by controller circuitry coupled to the touch sensor, and can be used to determine the location of the touch.

[0035] One particular embodiment of the invention is illustrated in FIG. 2A. The touch sensor 201 includes two multilayered structures 240, 245 separated by a gap 215. The top structure 240 is preferably flexible and the bottom structure layer 245 may be flexible or rigid. The top and bottom structures 240, 245 may be composed of transparent materials. Transparent touch screens are suitable for placement over a display device such as a liquid crystal display (LCD), or cathode ray tube (CRT) to create an integrated touch screen/display.

[0036] The top structure 240 includes a supporting layer 205 and a first conductive layer 210 with an optional protective coating 212. The components of the top structure 240 are preferably formed of flexible materials.

[0037] The bottom structure layer 245 may include a substrate 230 and a second conductive layer 220 that may also optionally be coated with a protective layer 218. The top and bottom structures 240, 245 are separated by a gap layer 215. Spacers 216 may be located within the gap 215 to maintain a predetermined distance between the top and bottom structures 240, 245, for example a space in the range 5 μm to 500 μm . The spacers 216 may be formed, for example, by screen printing UV curable material onto the bottom protective layer 218 or conductive layer 220 in a pattern of appropriate dimensions. Adjacent spacers may be separated from each other by a distance of between 20 μm to 5 mm.

[0038] The top supporting layer 205 may be used as an insulator for the top conductive layer 210 to reduce the effect of external capacitance on the touch sensor 201. External capacitance causes capacitive coupling between the touch sensor 201 and earth ground, and a resultant decrease in the signal to noise ratio of the touch location signal. Insulating the top conductive layer 210 with the top supporting layer 205 reduces the effect of external capacitance. The properties of the top supporting layer may be chosen to decrease capacitive coupling through the top supporting layer 205. Capacitive coupling may be decreased, for example, by using a top supporting layer 205 with appropriate material properties or thickness. In some embodiments, the dielectric thickness of the top supporting layer 205 may be formed to be greater than the dielectric thickness between the first and second conductive layers 210, 220. The dielectric thickness takes into account the actual thickness and the dielectric properties of the material over which the thickness is measured, and is proportional to the actual thickness multiplied by the relative permittivity of the material over which the thickness is measured. The dielectric thickness of the supporting layer 205 may be at least as thick as the minimum dielectric thickness between the deflected first conductive layer 210 and the second conductive layer 220. This configuration may be used to reduce external capacitive effects so that a change in capacitance induced by the deflection of the top conductive layer 210 is predominant.

[0039] The conductive layers 210, 220 are typically composed of thin sheets of conductive material. The conductive layers 210, 220 may be made as thin as possible while maintaining durability and continuity. In applications requiring a transparent touch sensor, a transparent conductive oxide such as indium tin oxide (ITO) or antimony tin oxide (ATO) may be used to form the conductors 210, 220. For example, the conductive layers 210, 220 may be comprised of ITO with a resistivity of approximately 10 to 50,000 ohms per square. In another example, the conductive layers 210, 220 may be comprised of ATO with a resistivity of approximately 10-50,000 ohms per square. The thickness of a conductive layer typically falls in the range 0.005 μm to 10 μm , although it may also have a thickness outside this range. Other transparent conductive materials may also be used for the conductive layers 210 and 220, such as an electrically conductive polymer. Suitable conductive polymers include polypyrrole, polyaniline, polyacetylene, polythiophene, polyphenylene vinylene, polyphenylene sulfide, poly p-phenylene, and polyheterocycle vinylene. An exemplary conductive polymer is poly (3,4-ethylenedioxythiophene), a substituted polythiophene, commonly referred to as PEDOT.